

Appendix C

Derivation of Y-Parameter Equations for the Grounded-Base Oscillator

The grounded-base crystal oscillator can be represented by the schematic diagram of Figure C-1.

Let the circuit be redrawn and the transistor replaced by a four-terminal network described by its Y -parameters. The diagram of Figure C-2 then results. If the transistor is represented by its Y -parameters, the feedback network must be represented by its Z -parameters if equation (A-12) is to be used.

For this analysis it is convenient to include the output resistance of the transistor in the load resistor R_T . This is accomplished by using a value of R_T which is equal to $R_L + (1/g_{ob})$. Often g_{ob} is negligible and the correction need not be used. The output capacity of the transistor will be lumped in parallel with L , thus making $y_{ob} = 0$ in the analysis. The reverse transfer admittance y_{rb} will be neglected to simplify the analysis.

The network which must be represented by its Z -parameters is given in Figure C-3.

From this circuit, the Z -parameters can be calculated using the following definitions:

$$\text{Input impedance} \quad Z_i = \left. \frac{V_1}{I_1} \right|_{I_2=0} \quad (\text{C-1})$$

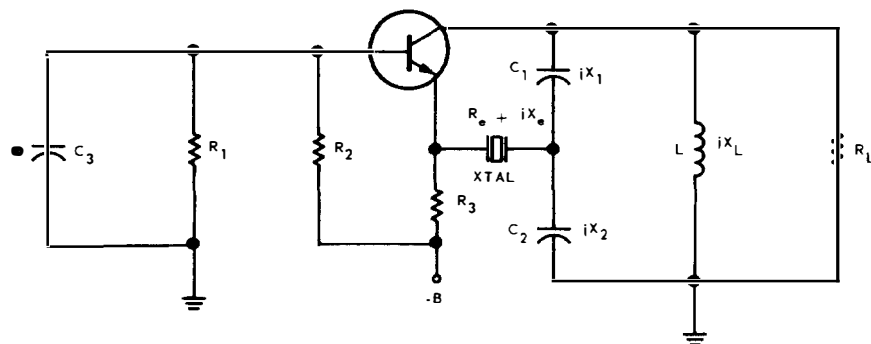


Figure C-1. Grounded-base oscillator: schematic diagram.

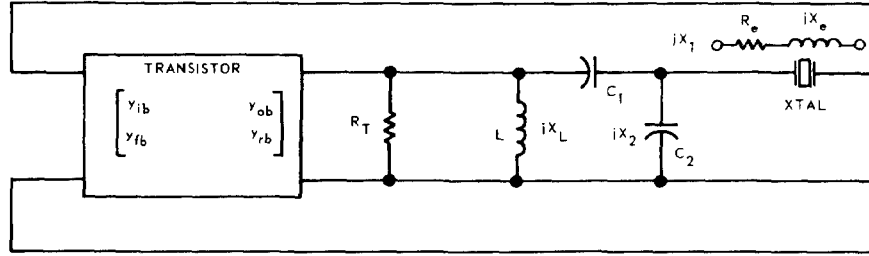


Figure C-2. Grounded-base oscillator: ac circuit diagram.

Output impedance
$$Z_o = \left. \frac{V_2}{I_2} \right|_{I_1=0} \quad (C-2)$$

Forward transfer impedance
$$Z_f = \left. \frac{V_2}{I_1} \right|_{I_2=0} \quad (C-3)$$

Reverse transfer impedance
$$Z_r = \left. \frac{V_1}{I_2} \right|_{I_1=0} \quad (C-4)$$

To simplify the analysis, it will be assumed that $X_1 + X_2 + X_L = 0$. This is approximately resonance for the tank circuit.

From equation (C-1) it can be seen that Z_i is merely the input impedance of the network with the output open-circuited and can be written by inspection as $Z_i = R_T$.

The forward transfer impedance is given by the ratio of V_2 to I_1 with the output open-circuited. In order to calculate this, it is convenient to first deter-

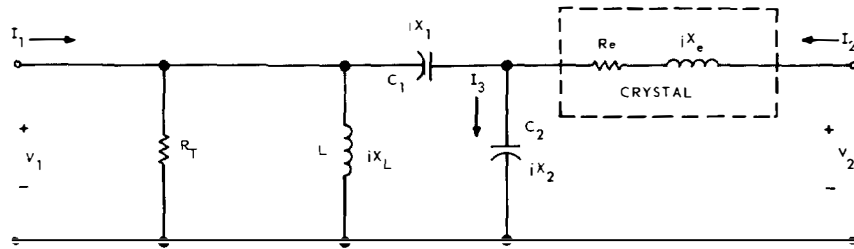


Figure C-3. Grounded-base oscillator feedback network: simplified diagram.

190 Appendix C

mine I_3 in terms of I_1 , which is given by

$$I_3 = \frac{I_1 \left(\frac{jR_T X_L}{R_T + jX_L} \right)}{\frac{jR_T X_L}{R_T + jX_L} + j(x_1 + x_2)} \quad (C-5)$$

Simplifying gives

$$I_3 = \frac{jI_1 R_T X_L}{-X_L(X_1 + X_2) + jR_T(X_1 + X_2 + X_L)}, \quad (C-6)$$

but

$$I_3 = \frac{V_2}{jX_2}.$$

Substituting this and making use of the assumption that

$$X_L + X_1 + X_2 = 0$$

gives

$$\frac{V_2}{I_1} = \frac{R_T X_2 X_L}{X_L(X_1 + X_2)} = \frac{R_T X_2}{X_1 + X_2} = \frac{-R_T X_2}{X_L}; \quad (C-7)$$

therefore

$$Z_f = -\frac{R_T X_2}{X_L}.$$

Since the network is composed entirely of reciprocal elements, the forward and reverse transfer impedances are equal, so that

$$Z_f = Z_r = -\frac{R_T X_2}{X_L}. \quad (C-8)$$

From equation (C-2), it can be seen that Z_o is merely the output impedance of the network with the input open-circuited. It is given by

$$Z_o = R_e + jX_e + \frac{\left[\left(\frac{jR_T X_L}{R_T + jX_L} \right) + jX_1 \right] jX_2}{\left[\left(\frac{jR_T X_L}{R_T + jX_L} \right) + jX_1 \right] + jX_2}. \quad (C-9)$$

Simplifying this gives

$$Z_o = R_e + jX_e + \frac{jX_2 [-X_1 X_L + jR_T(X_1 + X_L)]}{jR_T(X_1 + X_2 + X_L) - X_L(X_1 + X_2)}. \quad (C-10)$$

Making use of the assumption $X_1 + X_2 + X_L = 0$ and further simplifying gives

$$Z_o = R_e + jX_e + \frac{R_T X_2 (X_1 + X_L) + jX_1 X_2 X_L}{X_L (X_1 + X_2)} \quad (C-11)$$

and

$$\frac{1}{\Delta Z} = \frac{1}{R_T X_2 (X_1 + X_L) + jX_1 X_2 X_L}. \quad (C-12)$$

These results can be substituted in the general equation for oscillation as developed in Appendix A:

$$y_{fb} Z_f + y_{ib} Z_o + y_{ob} Z_i + y_{rb} Z_r + \Delta y_b \Delta Z + 1 = 0. \quad (C-13)$$

Since y_{ob} is being accounted for the feedback network, and since y_{rb} is assumed to be zero, $\Delta y = y_{ib} y_{ob} - y_{fb} y_{ob} = 0$. This simplifies equation (C-13) to

$$y_{fb} Z_f + y_{ib} Z_o + 1 = 0. \quad (C-14)$$

Substituting for Z_f and Z_o gives

$$\frac{-y_{fb} R_T X_2}{X_L} + (g_{ib} + jb_{ib}) \left[R_e + jX_e + \frac{R_T X_2^2 - jX_1 X_2 X_L}{X_L^2} \right] + 1 = 0. \quad (C-15)$$

Substituting $y_{fb} = g_{fb} + jb_{fb}$ and $y_{ib} = g_{ib} + jb_{ib}$ gives

$$\frac{-(g_{fb} + jb_{fb}) R_T X_2}{X_L} + (g_{ib} + jb_{ib}) \left[R_e + jX_e + \frac{R_T X_2^2 - jX_1 X_2 X_L}{X_L^2} \right] + 1 = 0. \quad (C-16)$$

Performing the indicated multiplications and collecting terms results in the following equation:

$$\begin{aligned} & -g_{fb} R_T X_2 - jb_{fb} R_T X_2 + g_{ib} R_e X_L + jg_{ib} X_e X_L + jb_{ib} R_e X_L - b_{ib} X_e X_L \\ & + \frac{g_{ib} R_T X_2^2}{X_L} - jg_{ib} X_1 X_2 + \frac{jR_T X_2^2 b_{ib}}{X_L} + b_{ib} X_1 X_2 + X_L = 0. \end{aligned} \quad (C-17)$$

This equation can be separated into real and imaginary components. The real

192 Appendix C

parts are

$$-g_{fb}R_TX_2 + g_{ib}R_eX_L - b_{ib}X_eX_L + \frac{g_{ib}R_TX_2^2}{X_L} + b_{ib}X_1X_2 + X_L = 0. \quad (C-18)$$

Substituting $g_{ib} = 1/R_{in}$ and simplifying gives

$$g_{fb} = \frac{1}{R_T} \left(\frac{X_L}{X_2} \right) \left[\frac{R_e + R_{in}}{R_{in}} \right] + \frac{1}{R_{in}} \left(\frac{X_2}{X_L} \right) + \frac{b_{ib}X_1}{R_T} - b_{ib} \left(\frac{X_e}{R_T} \right) \left(\frac{X_L}{X_2} \right) = 0. \quad (C-19)$$

The imaginary parts are

$$-b_{fb}R_TX_2 + g_{ib}X_eX_L + b_{ib}R_eX_L - g_{ib}X_1X_2 + \frac{R_TX_2^2b_{ib}}{X_L} = 0. \quad (C-20)$$

Again substituting $g_{ib} = 1/R_{in}$ and simplifying gives

$$X_e = b_{fb}R_TR_{in} \left(\frac{X_2}{X_L} \right) + X_1 \left(\frac{X_2}{X_L} \right) - b_{ib}R_{in} \left[R_e + R_T \left(\frac{X_2}{X_L} \right)^2 \right]. \quad (C-21)$$

The optimum value of X_L/X_2 with respect to transistor gain can be found by differentiating equation (C-19):

$$\frac{d(g_{fb})}{d(X_L/X_2)} = \frac{1}{R_T} \left[\frac{R_e + R_{in}}{R_{in}} \right] - \frac{1}{R_{in}} \left(\frac{X_2}{X_L} \right)^2 - b_{ib} \left(\frac{X_e}{R_T} \right). \quad (C-22)$$

If it is required that the crystal operate at series resonance $X_e = 0$ or if b_{ib} is negligible, then equation (C-22) simplifies to

$$\frac{d(g_{fb})}{d(X_L/X_2)} = \frac{1}{R_T} \left[\frac{R_e + R_{in}}{R_{in}} \right] - \frac{1}{R_{in}} \left(\frac{X_2}{X_L} \right)^2. \quad (C-23)$$

Solving this for X_L/X_2 gives

$$X_L/X_2 = -\sqrt{R_T/(R_e + R_{in})} \quad (C-24)$$

The minimum g_{fb} then is given by

$$|g_{fb}|_{\min} = \left| -\frac{2}{R_{in}} \sqrt{(R_e + R_{in})/R_T} + b_{ib}(X_1/R_T) \right|. \quad (C-25)$$

NOTE. This assumes that the crystal is at series resonance, $X_e = 0$.